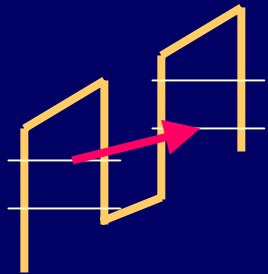


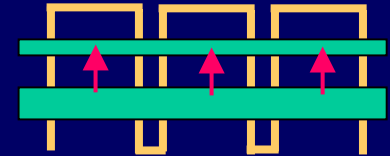
Terahertz Quantum-Staircase and Quantum-Parallel Laser Designs for GaAs/AlGaAs and SiGe/Si



HH 1
LH 1

Richard Soref

Air Force Research Laboratory



Quantum Staircase Laser

- *Highly simplified cascade
- *No injector sections
- *Identical quantum wells
- *Strain-balanced SiGe/Si
- *PIP and NIN laser designs

Quantum Parallel Laser

- *Simple flatband superlattice
- *Low bias voltage
- *"Super Superlattice" is the optimum design
- *PIPIP and NININ designs

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Principles and Limitations of Electrically-Injected Unipolar QSLs and QPLs

Quantum Staircase Injectorless Approaches:

1. Non-resonant-tunn. diagonal transition scheme: 1 QW
2. Phonon-depopulated resonant tunneling scheme: 3 QW per period, vertical transition
3. 1 QW per period resonant scheme: vertical transition

Limitations:

- At $\lambda < 20 \mu\text{m}$, bias $> 90 \text{ kV/cm}$
- 500 to 1000 periods are required.

Quantum Parallel Superlattice Approach:

- Inter-miniband lasing (4 levels in effect)
- Photon energy is less than LO phonon energy
- Appl bias bucks out built-in voltage from n/n⁺ contacts

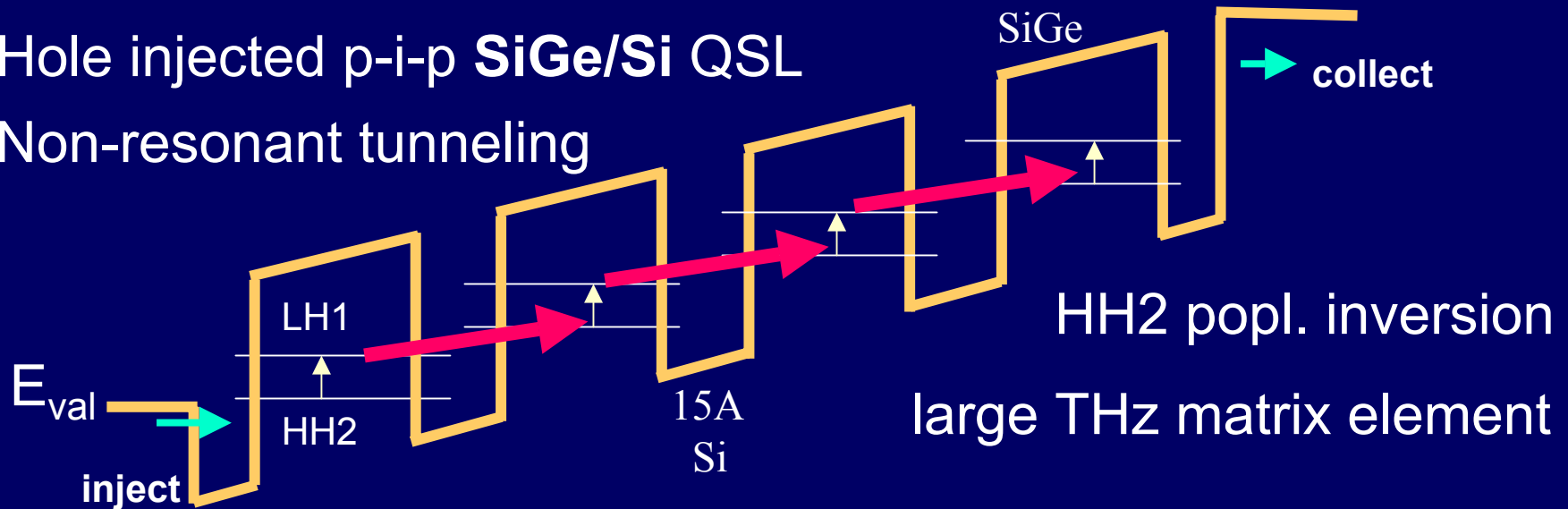
Limitations:

- Low gain at $\lambda < 12 \mu\text{m}$, SiGe
- 500 to 1000 periods are required.
- Must use $T < 25 \text{ K}$ in GaAs

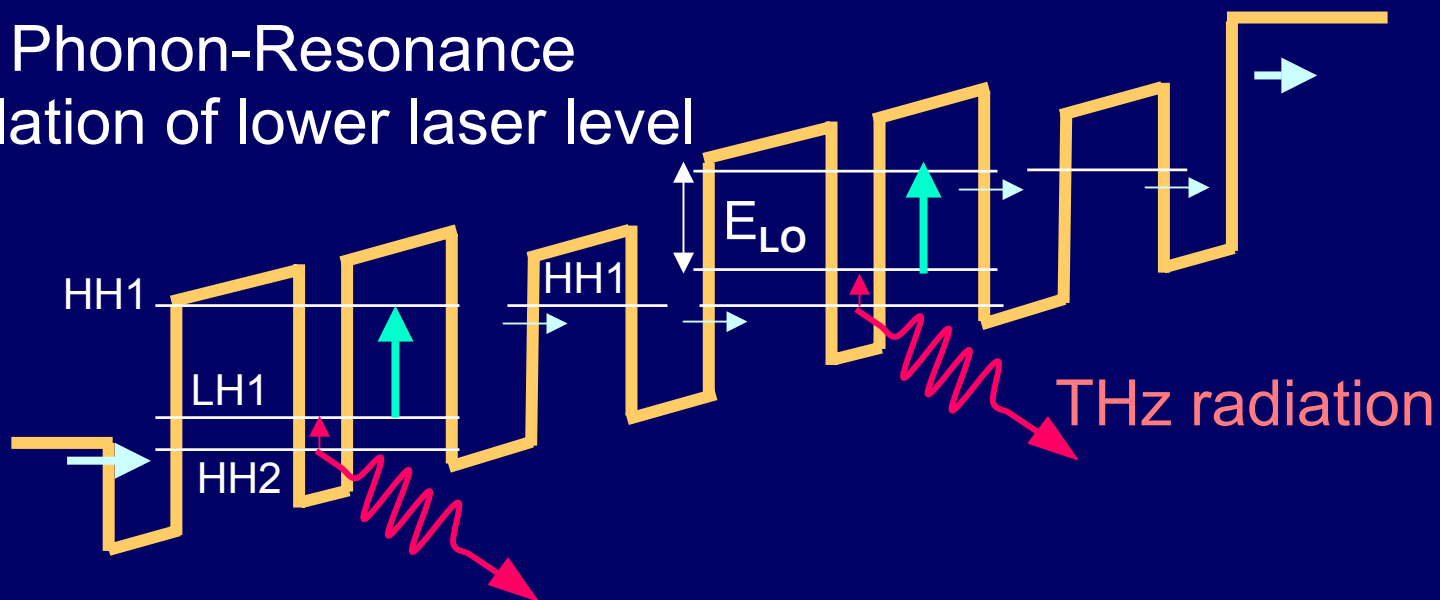
Hole Cascade via Inter-Well Diagonal Radiative Transition (designed in collaboration with University of Leeds team)

Hole injected p-i-p **SiGe/Si** QSL

Non-resonant tunneling

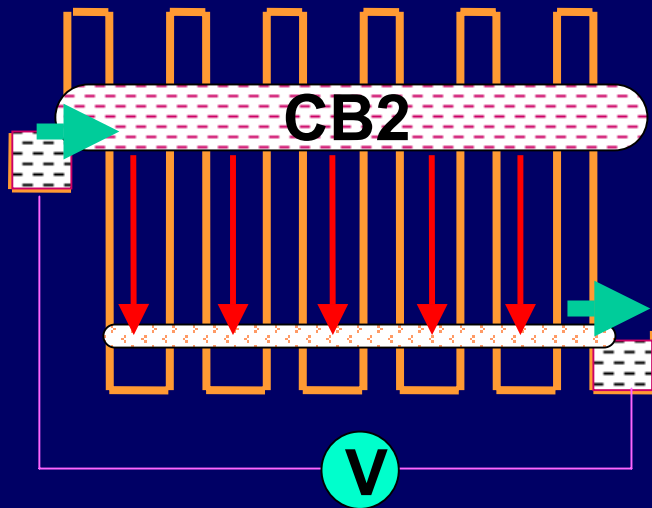


Phonon-Resonance
depopulation of lower laser level



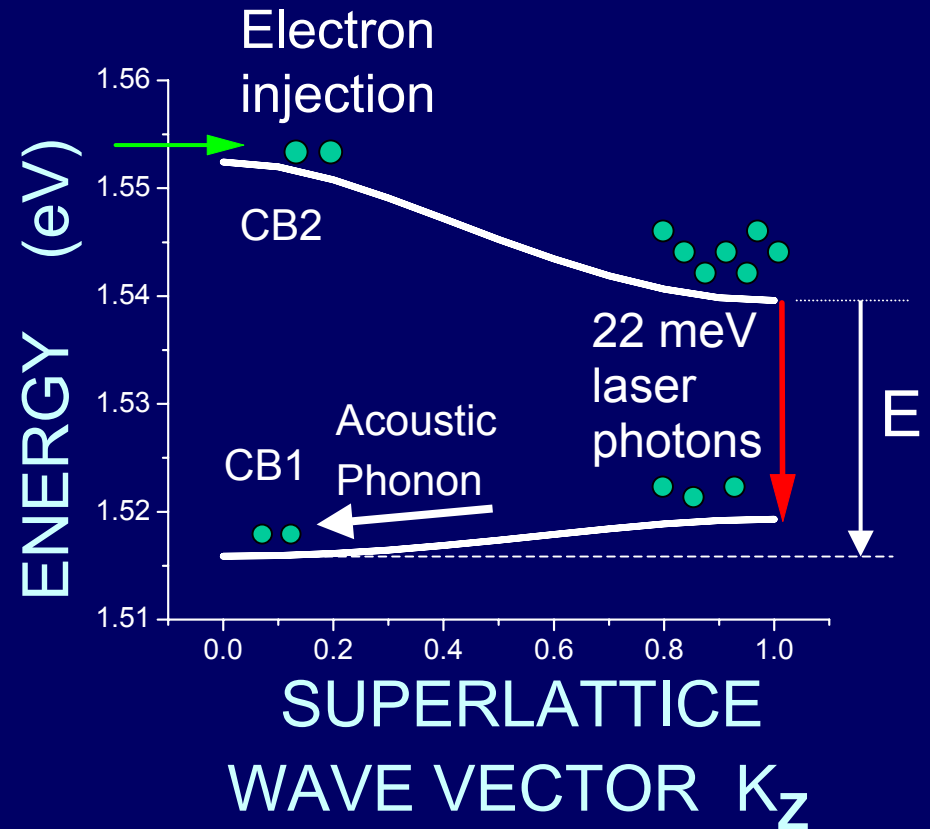
QPL: GaAs/Al_{0.15}Ga_{0.85}As 200Å/24Å Superlattice

*Band Diagram
In Real Space*



n-Ga(0.7)Al(0.3) elec. injector
n-GaAs collector
GaAs quantum wells
Ga(0.85)Al(0.15)As barriers

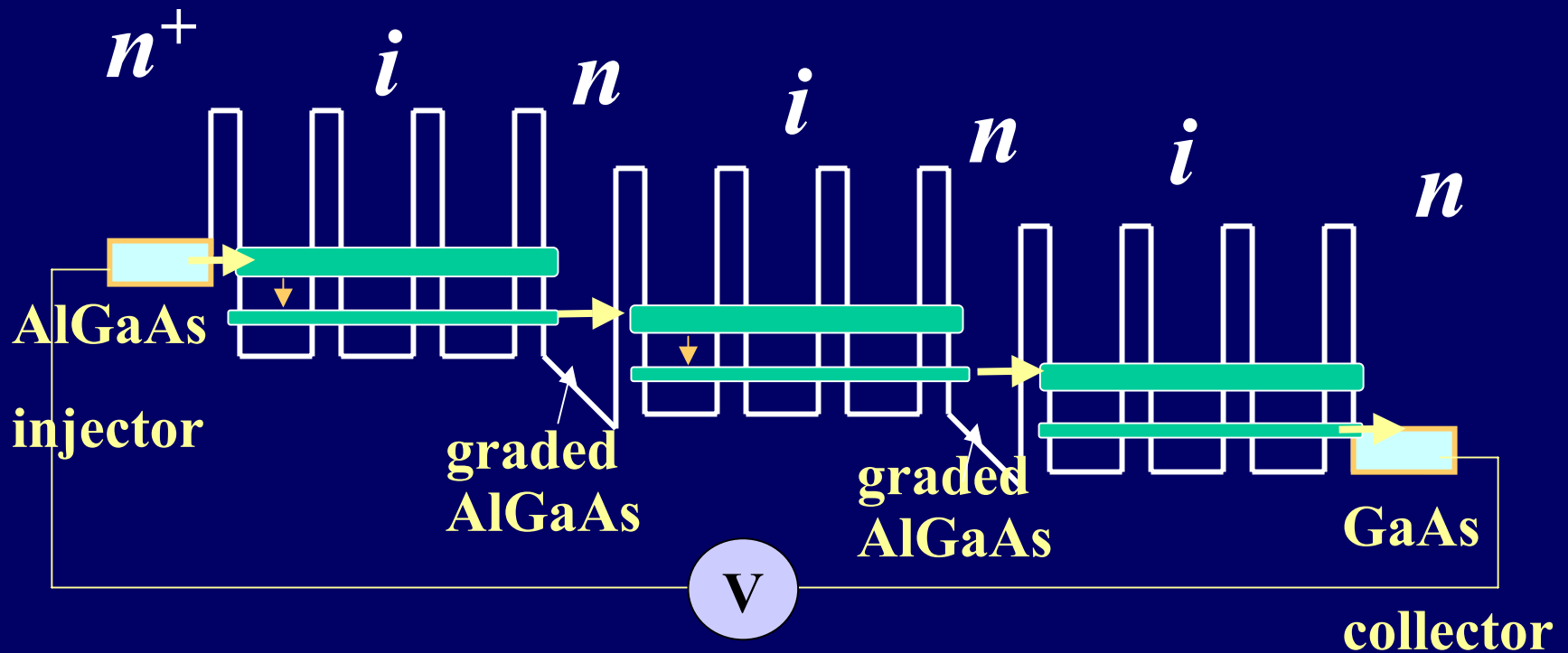
*Dispersion Diagram:
CB2, CB1 Minibands*



$E < 36$ meV, LO phonon emission
is suppressed.

QPL constructed of “stitched” parallel regions; the “super super lattice”

Resonant tunneling of electrons between flatband SLs is obtained by the **composition-gradient** in the n-doped AlGaAs transfer barriers



Ballistic transport in each superlattice

Ways to Accelerate Future Developments— Possible Collaborations, Leverage, Improvement of Approach

- Try the new QPL in III-Vs and IV-IVs
- Try the phonon-depop QSL in SiGe (64 meV, 300K lasing?)
- Try the new GaN/AlGaIn QSL (90 meV phonon-depop, CW at 300K?)
G. Sun and R. Soref,
APL manuscript
- New STTRs from AFOSR and ONR
- On-going STTRs
- European Union SiGe THz Project
- MURI from AFOSR and/or ONR
- Leeds EPSRC grant: n-type QCLs, and mid-IR QCLs

CONCLUSIONS...CHALLENGES...QUESTIONS

Conclusions:

- * new SiGe and GaAs THz laser designs: simpler alternatives to the cascade, CVD

Challenges:

- * several microns of epitaxy required
- * non resonant staircase...as with Leeds
- * tunneling via graded barriers in SSL

Questions:

- * domain formation? carrier cooling?
- * good mode overlap in SSL?
- * mode loss due to n-barriers in SSL?